

Data sheet acquired from Cypress Semiconductor Corporation. Data sheet modified to remove devices not offered.

CY74FCT16652T CY74FCT162652T

SCCS061 - July 1994 - Revised March 2000

Features

- FCT-E speed at 3.8 ns
- · Power-off disable outputs permits live insertion
- · Edge-rate control circuitry for significantly improved noise characteristics
- Typical output skew < 250 ps
- ESD > 2000V
- TSSOP (19.6-mil pitch) and SSOP (25-mil pitch) packages
- Industrial temperature range of -40°C to +85°C
- $V_{CC} = 5V \pm 10\%$

CY74FCT16652T Features:

- 64 mA sink current, 32 mA source current
- Typical V_{OLP} (ground bounce) <1.0V at V_{CC} = 5V, $T_A = 25^{\circ}C$

CY74FCT162652T Features:

· Balanced 24 mA output drivers

Logic Block Diagrams

- · Reduced system switching noise
- Typical V_{OLP} (ground bounce) <0.6V at $V_{CC} = 5V_{p}$ T_A= 25°C

16-Bit Registered Transceivers

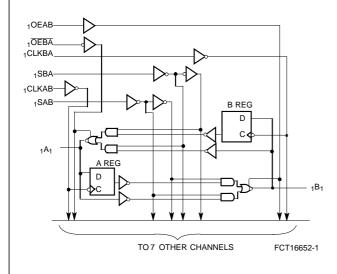
Functional Description

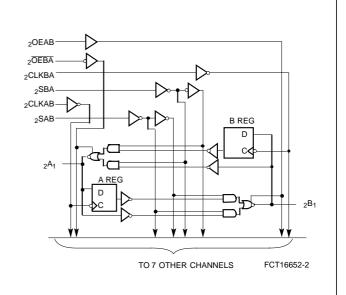
These 16-bit, high-speed, low-power, registered transceivers that are organized as two independent 8-bit bus transceivers with three-state D-type registers and control circuitry arranged for multiplexed transmission of data directly from the input bus or from the internal storage registers. OEAB and OEBA control pins are provided to control the transceiver functions. SAB and SBA control pins are provided to select either real-time or stored data transfer.

Data on the A or B data bus, or both, can be stored in the internal D flip-flops by LOW-to-HIGH transitions at the appropriate clock pins (CLKAB or CLKBA), regardless of the select or enable control pins. When SAB and SBA are in the real-time transfer mode, it is also possible to store data without using the internal D-type flip-flops by simultaneously enabling OEAB and OEBA. In this configuration, each output reinforces its input. Thus, when all other data sources to the two sets of bus lines are at high impedance, each set of bus lines will remain at its last state. The output buffers are designed with a power-off disable feature that allows live insertion of boards.

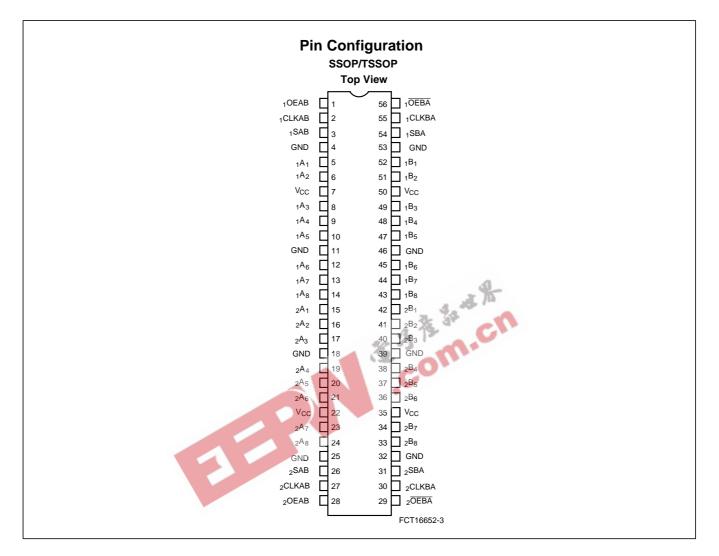
The CY74FCT16652T is ideally suited for driving high-capacitance loads and low-impedance backplanes.

The CY74FCT162652T has 24-mA balanced output drivers with current-limiting resistors in the outputs. This reduces the need for external terminating resistors and provides for minimal undershoot and reduced ground bounce. The CY74FCT162652T is ideal for driving transmission lines.









Pin Description

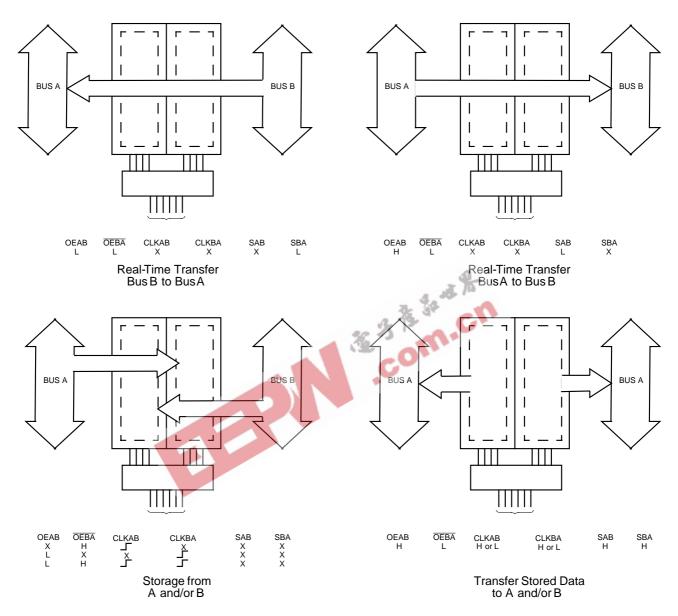
Name	Description
A	Data Register A Inputs Data Register B Outputs
В	Data Register B Inputs Data Register A Outputs
CLKAB, CLKBA	Clock Pulse Inputs
SAB, SBA	Output Data Source Select Inputs
OEAB, OEBA	Output Enable Inputs



Function Table^[1]

		Inpu	Its			Data	I/O ^[2]	
OEAB	OEBA	CLKAB	CLKBA	SAB	SBA	A	В	Operation or Function
L	H H	H or L	H or L J	X X	X X	Input	Input	Isolation Store A and B Data
X H	H H	л Г	HorL ⊿	X X ^[3]	X X	Input Input	Unspecified ^[2] Output	Store A, Hold B Store A in Both Registers
L	X L	H or L	7	X X	X X ^[3]	Unspecified ^[2]	Input Input	Hold A, Store B Store B in both Registers
L	L	Х	Х	Х	L	Output	Input	Real Time B Data to A Bus Stored B Data to A Bus
L	L	X	H or L	Х	Н			
Н	Н	X	Х	L	Х	Input	Output	Real Time A Data to B Bus Stored A Data to B Bus
Н	н	H or L	Х	Н	Х			
Н	L	H or L	H or L	Н	Н	Output	Output	Stored A Data to B Bus and Stored B Data to A Bus
Notes: 1. H = HIGH Voltage Level L = LOW Voltage Level X = Don't Care								





Maximum Ratings^[4]

(Above which the useful life may be impaired. For user guide-lines, not tested.)

Storage TemperatureCom'l -55°C to +125°C
Ambient Temperature with Power AppliedCom'l -55°C to +125°C
DC Input Voltage0.5V to +7.0V
DC Output Voltage0.5V to +7.0V
DC Output Current (Maximum Sink Current/Pin)60 to +120 mA

Power Dissipation	1.0W
Static Discharge Voltage	>2001V
(per MIL-STD-883, Method 3015)	

Operating Range

Range	Ambient Temperature	v _{cc}
Industrial	–40°C to +85°C	5V ± 10%

4. Stresses greater than those listed under Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Note:



DC Electrical Characteristics Over the Operating Range

Parameter	Description	Test Conditions ^[5]	Min.	Typ. ^[6]	Max.	Unit			
V _{IH}	Input HIGH Voltage	Logic HIGH Level	2.0			V			
V _{IL}	Input LOW Voltage	Logic LOW Level			0.8	V			
V _H	Input Hysteresis			100		mV			
V _{IK}	Input Clamp Diode Voltage	V _{CC} =Min., I _{IN} =-18 mA		-0.7	-1.2	V			
I _{IH}	Input HIGH Current	V _{CC} =Max., V _I =V _{CC}			±1	μΑ			
IIL	Input LOW Current	V _{CC} =Max., V _I =GND			±1	μΑ			
I _{OZH}	High Impedance Output Current (Three-State Output pins)	V _{CC} =Max., V _{OUT} =2.7V			±1	μA			
I _{OZL}	High Impedance Output Current (Three-State Output pins)	V _{CC} =Max., V _{OUT} =0.5V			±1	μA			
I _{OS}	Short Circuit Current ^[8]	V _{CC} =Max., V _{OUT} =GND	-80	-140	-200	mA			
I _O	Output Drive Current ^[8]	V _{CC} =Max., V _{OUT} =2.5V	-50		-180	mA			
I _{OFF}	Power-Off Disable	V _{CC} =0V, V _{OUT} ≤4.5V ^[7]			±1	μΑ			
Output Dr	Dutput Drive Characteristics for CY74FCT16652T								

Output Drive Characteristics for CY74FCT16652T

Parameter	Description	Test Conditions ^[5]	Min.	Typ. ^[6]	Max.	Unit
V _{OH}	Output HIGH Voltage	V _{CC} =Min., I _{OH} =-3 mA	2.5	3.5		V
		V _{CC} =Min., I _{OH} =-15 mA	2.4	3.5		
		V _{CC} =Min., I _{OH} =-32 mA	2.0	3.0		
V _{OL}	Output LOW Voltage	V _{CC} =Min., I _{OL} =64 mA		0.2	0.55	V

Output Drive Characteristics for CY74FCT162652T

Parameter	Description	Test Conditions ^[5]	Min.	Typ. ^[6]	Max.	Unit
I _{ODL}	Output LOW Current ^[8]	V_{CC} =5V, V_{IN} =V _{IH} or V_{IL} , V_{OUT} =1.5V	60	115	150	mA
I _{ODH}	Output HIGH Current ^[8]	V_{CC} =5V, V_{IN} =V _{IH} or V_{IL} , V_{OUT} =1.5V	-60	–115	-150	mA
V _{OH}	Output HIGH Voltage	V _{CC} =Min., I _{OH} =-24 mA	2.4	3.3		V
V _{OL}	Output LOW Voltage	V _{CC} =Min., I _{OL} =24 mA		0.3	0.55	V

Capacitance ($T_A = +25^{\circ}C$, f = 1.0 MHz)

Parameter	Description ^[10]	Test Conditions	Тур.	Max.	Unit
C _{IN}	Input Capacitance	$V_{IN} = 0V$	4.5	6.0	pF
C _{OUT}	Output Capacitance	V _{OUT} = 0V	5.5	8.0	pF

Notes:

For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type. Typical values are at V_{CC} =5.0V, +25°C ambient. Tested at T_A= +25°C. 5. 6.

7.

Not more than one output should be tested at one time. Duration of the test should not exceed one second.
 Duration of the condition cannot exceed one second.
 This parameter is measured at characterization but not tested.



Power Supply Characteristics

Param.	Description	Test Condition	ons ^[11]	Min.	Typ. ^[12]	Max.	Unit
I _{CC}	Quiescent Power Supply Current	V _{CC} =Max.	V _{IN} ≤0.2V V _{IN} ≥V _{CC} −0.2V	_	5	500	μA
ΔI_{CC}	Quiescent Power Supply Current TTL Inputs HIGH	V _{CC} = Max. V _{IN} =3.4V ^[13]		_	0.5	1.5	mA
I _{CCD}	Dynamic Power Supply Current ^[14]	V _{CC} =Max. Outputs Open OEAB=OEAB=GND One Input Toggling 50% Duty Cycle	V _{IN} =V _{CC} or V _{IN} =GND		75	120	μΑ/ MHz
I _C Total Power Supply Current ^{[15}	Total Power Supply Current ^[15]	Outputs Open $f_0=10$ MHz (CLKBA) 50% Duty Cycle OEAB=OEBA=GND One-Bit Toggling $f_1=5$ MHz 50% Duty Cycle $V_{CC}=Max.$ Outputs Open $f_0=10$ MHz (CLKBA)	V _{IN} =V _{CC} or V _{IN} =GND		0.8	1.7	mA
			V _{IN} =3.4V or V _{IN} =GND	_	1.3	3.2	mA
			V _{IN} =V _{CC} or V _{IN} =GND	_	3.8	6.5 ^[16]	mA
			V _{IN} =3.4V or V _{IN} =GND		8.3	20.0 ^[16]	mA

Notes:

- Notes:

 11. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.

 12. Typical values are at $V_{CC}=5.0V + 25^{\circ}$ ambient.

 13. Per TTL driven input $(V_{IN}=3.4V)$; all other inputs at V_{CC} or GND.

 14. This parameter is not directly testable, but is derived for use in Total Power Supply calculations.

 15. $I_C = I_{OUESCENT} + I_{INPUTS} + I_{DYNAMIC}$
 $I_C = I_{OC} + \Delta I_{CC} D_{II} N_{T} + I_{CC} (f_0/2 + f_1 N_1)$
 $I_{CC} = Quiescent Current with CMOS input levels$
 $\Delta I_{CC} = Power Supply Current for a TTL HIGH input (V_{IN}=3.4V)$
 $D_H = Duty Cycle for TTL inputs HIGH$
 $N_T = Number of TTL inputs at <math>D_H$
 $I_{CCD} = Dynamic Current caused by an input transition pair (HLH or LHL)

 <math>f_0 = Clock$ frequency for registered devices, otherwise zero

- - f_0 = Clock frequency for registered devices, otherwise zero
- $f_1 = Input signal frequency$ $<math>N_1 = Number of inputs changing at f_1$ All currents are in milliamps and all frequencies are in megahertz.Values for these conditions are examples of the I_{CC} formula. These limits are specified but not tested.16.



Switching Characteristics Over the Operating Range^[17]

			16652AT 162652AT		
Parameter	Description	Min.	Max.	Unit	Fig. No. ^[18]
t _{PLH} t _{PHL}	Propagation Delay Bus to Bus	1.5	6.3	ns	1, 3
t _{PZH} t _{PHL}	Output Enable Time OEAB or OEBA to Bus	1.5	9.8	ns	1, 7, 8
t _{PHZ} t _{PLZ}	Output Disable Time OEAB or OEBA to Bus	1.5	6.3	ns	1, 7, 8
t _{PLH} t _{PHL}	Propagation Delay Clock to Bus	1.5	6.3	ns	1, 5
t _{PLH} t _{PHL}	Propagation Delay SBA or SAB to Bus	1.5	7.7	ns	1, 5
t _{SU}	Set-Up time HIGH or LOW Bus to Clock	2.0	a	ns	4
t _H	Hold Time HIGH or LOW Bus to Clock	1.5	[/lb	ns	4
t _W	Clock Pulse Width HIGH or LOW	5.0	÷	ns	5
t _{SK(O)}	Output Skew ^[19]	3 -0	0.5	ns	

			1 - Sec.				
		CY74FCT CY74FCT		CY74FCT CY74FCT			
Parameter	Description	Min.	Max.	Min.	Max.	Unit	Fig. No. ^[18]
t _{PLH} t _{PHL}	Propagation Delay Bus to Bus	1.5	5.4	1.5	3.8	ns	1, 3
t _{PZH} t _{PHL}	Output Enable Time OEAB or OEBA to Bus	1.5	7.8	1.5	4.8	ns	1, 7, 8
t _{PHZ} t _{PLZ}	Output Disable Time OEAB or OEBA to Bus	1.5	6.3	1.5	4.0	ns	1, 7, 8
t _{PLH} t _{PHL}	Propagation Delay Clock to Bus	1.5	5.7	1.5	3.8	ns	1, 5
t _{PLH} t _{PHL}	Propagation Delay SBA or SAB to Bus	1.5	6.2	1.5	4.2	ns	1, 5
t _{SU}	Set-Up Time HIGH or LOW Bus to Clock	2.0	_	2.0	_	ns	4
t _H	Hold Time HIGH or LOW Bus to Clock	1.5	_	0.0	-	ns	4
t _W	Clock Pulse Width HIGH or LOW	5.0	—	3.0	-	ns	5
t _{SK(O)}	Output Skew ^[19]	_	0.5	_	0.5	ns	

Notes:

Minimum limits are specified, but not tested, on propagation delays.
 See "Parameter Measurement Information" in the General Information section.
 Skew between any two outputs of the same package switching in the same direction. This parameter ensured by design.



Ordering Information CY74FCT16652

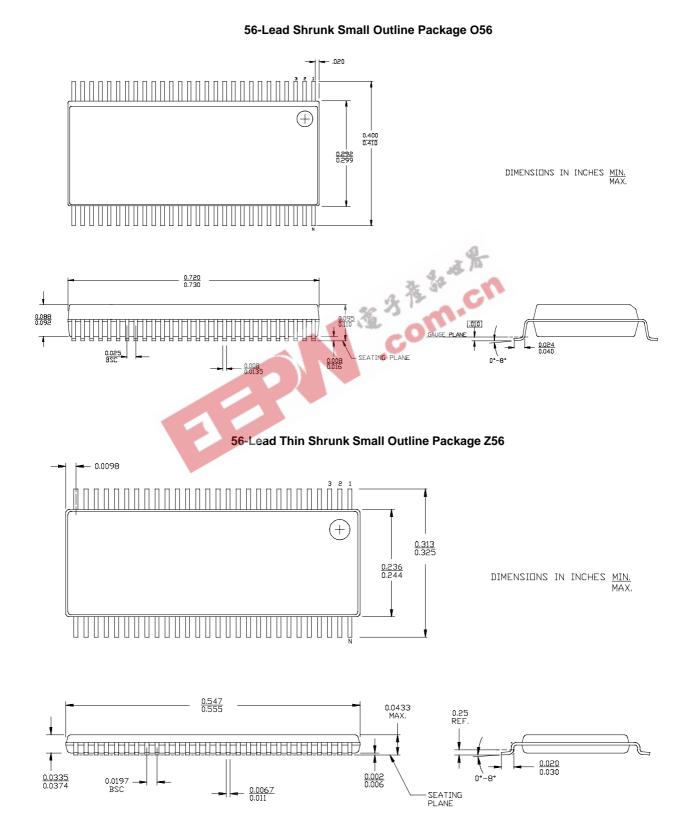
Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
3.8	CY74FCT16652ETPACT	Z56	56-Lead (240-Mil) TSSOP	Industrial
	CY74FCT16652ETPVC/PVCT	O56	56-Lead (300-Mil) SSOP	
5.4	CY74FCT16652CTPVC/PVCT	O56	56-Lead (300-Mil) SSOP	Industrial
6.3	CY74FCT16652ATPVC/PVCT	O56	56-Lead (300-Mil) SSOP	Industrial

Ordering Information CY74FCT162652

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
3.8	74FCT162652ETPACT	Z56	56-Lead (240-Mil) TSSOP	Industrial
	CY74FCT162652ETPVC	O56	56-Lead (300-Mil) SSOP	
	74FCT162652ETPVCT	O56	56-Lead (300-Mil) SSOP	
5.4	74FCT162652CTPACT	Z56	56-Lead (240-Mil) TSSOP	Industrial
	CY74FCT162652CTPVC	O56	56-Lead (300-Mil) SSOP	
	74FCT162652CTPVCT	O56	56-Lead (300-Mil) SSOP	
6.3	CY74FCT162652ATPVC	O56	56-Lead (300-Mil) SSOP	Industrial
	74FCT162652ATPVCT	O56	56-Lead (300-Mil) SSOP	



Package Diagrams



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